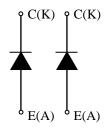
FEATURES

- * Low VF diode module.
- * Low noise recovery: Ultra soft fast recovery diode.
- * High reverse recovery capability: Super HiRC Structure.
- * High reliability, high durability diodes.
- * Isolated heat sink (terminal to base).

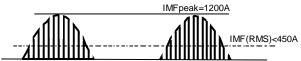
CIRCUIT DIAGRAM



ABSOLUTE MAXIMUM RATINGS (TC=25°C)

Item			Symbol	Unit	MDM1200H45E2	
Repetitive Peak Reverse Voltage			V_{RRM}	V	4,500	
Forward Current		AC peak	I MFpeak	Α	1,200	
		1ms	I Fpulse	A	2,400	
Junction Temperature			Tj	°C	-40 ∼ +125	
Storage Temperature			Tstg	°C	-50 \sim +125 (1)	
Isolation Test	Terminals	Terminals-base		V _{RMS}	8,400 (AC 1 minute)	
Voltage	Terminal 1-Terminal 2		V _{ISO} T-T		8,400 (AC 1 minute)	
Screw Torque	Terminals	Terminals (M8)		N∙m	10 (2)	
	Mounting	(M6)	-		6 (3)	

Notes: (1) Terminal temperature shall not exceed the specified temperature in any operation. (2) Recommended Value 9±1N·m (3) Recommended Value 5.5±0.5N·m



ELECTRICAL CHARECTERISTICS

Item	Symbol	Unit	Min.	Тур.	Max.	Test Conditions
Repetitive Reverse Current	I _{RRM}	mΑ	1	2.0	25	VAK=4,500V, Tj=125°C
Forward Voltage Drop	VF	V	-	3.4	3.9	IF=1,200A, Tj=125°C
Reverse Recovery Time	trr	μS	-	0.9	1.8	Vcc=2,600V, IF=1,200A, Ls=180nH
Reverse Recovery Loss	E _{rr(10%)}	J/P		3.4	5.1	Tj=125°C Rg=3.3Ω(4)

Notes:(4) Counter arm; MBN1200H45E2 VGE=+/-15V

Rg value is the test condition's value for evaluation of the switching times, not recommended value.

Please, determine the suitable Rg value after the measurement of switching waveforms

(overshoot voltage, etc.) with appliance mounted.

PACKAGE CHARECTERISTICS

Item	Symbol	Unit	Min.	Тур.	Max.	Test Conditions
Terminal Resistance	RCE	$m\Omega$	-	0.3	-	per arm
Terminal Stray Inductance	Lsce	nΗ	-	42	-	per arm
Thermal Impedance	Rth(j-c)	K/W	-	-	0.017	Junction to case (per arm)
Comparative tracking index	CTI		-	600	-	
Contact Thermal Impedance	Rth(c-f)	K/W	ı	0.007	ı	Case to fin (λgrease=1W/(m⋅K), heat-sink flatness ≤50um)

^{*} Please contact our representatives at order.

^{*} For improvement, specifications are subject to change without notice.

^{*} For actual application, please confirm this spec sheet is the newest revision.

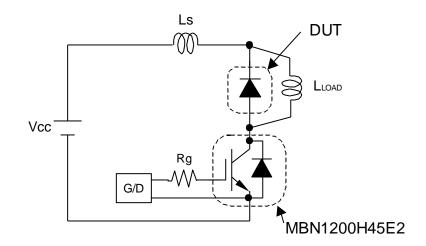


Fig.1 Switching test circuit

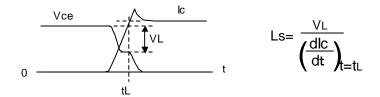


Fig.2 Definition of stray inductance

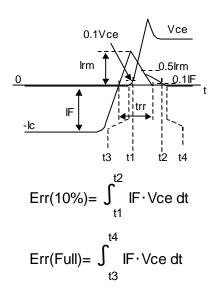
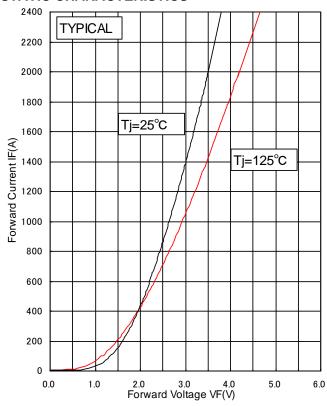


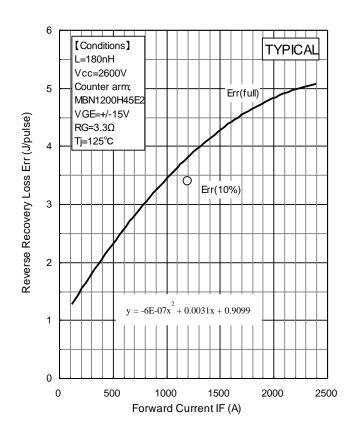
Fig.3 Definition of switching loss

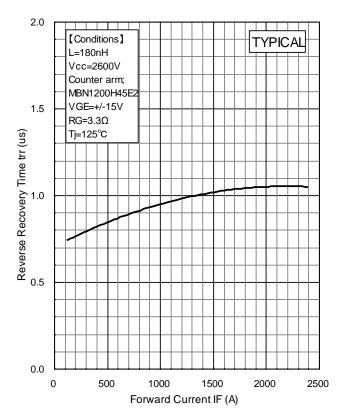
STATIC CHARACTERISTICS



Forward Voltage of diode

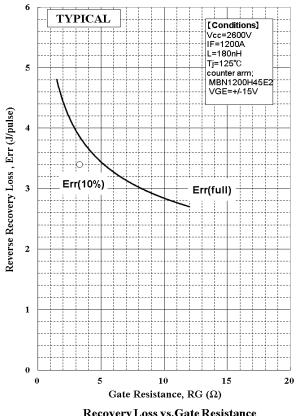
DYNAMIC CHARACTERISTICS



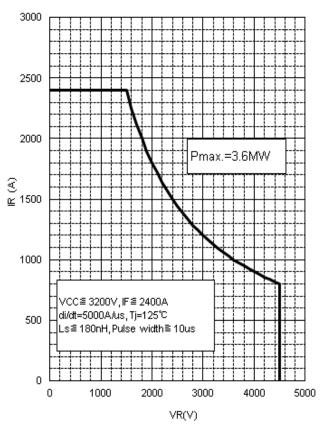


Recovery Loss vs. Forward Current

Recovery Time vs. Forward Current

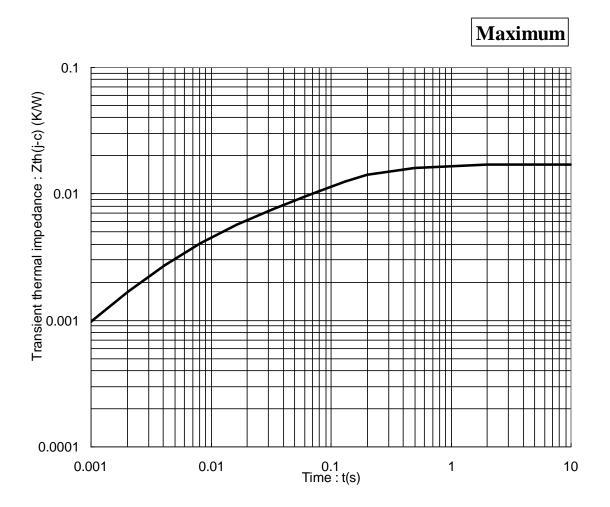


Recovery Loss vs. Gate Resistance



RecSOA

TRANSIENT THERMAL IMPEDANCE



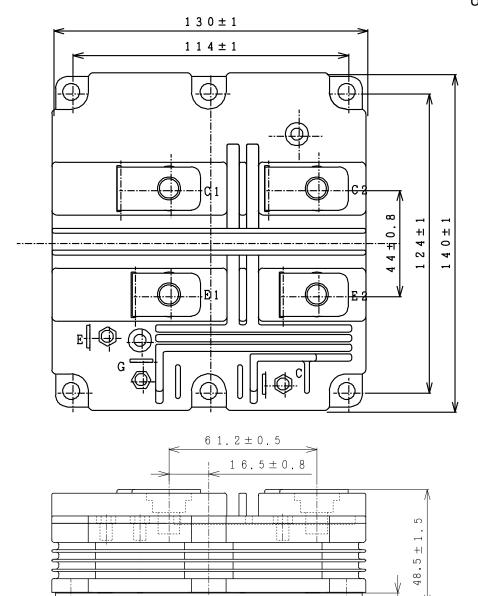
Transient Thermal Impedance Curve

Curve Approximation Model Σ rth[n]*(1-exp(-t/τth[n]))

n	1	2	3	4	Unit
τ th[n]	3.98E-01	6.81E-02	1.32E-02	3.16E-04	sec
rth[n,IGBT]	1.02E-02	3.35E-03	3.19E-03	2.87E-04	K/W

OUTLINE DRAWING

Unit in mm



Weight: 1050(g)

Material declaration

Please note the following materials are contained in the product in order to keep product characteristic and reliability level.

Material	Contained part
Lead (Pb) and its compounds	Solder

Minebea POWER SEMICONDUCTORS

Notices

- 1. Since mishandling of semiconductor devices may cause malfunctions, please be sure to read "Precautions for Safe Use and Notices" in the individual brochure before use.
- 2. When designing an electronic circuit using semiconductor devices, please do not exceed the absolute maximum rating specified for the device under any external fluctuations. And for pulse applications, please also do not exceed the "Safe Operating Area (SOA)".
- Semiconductor devices may sometimes break down by accidental or unexpected surge
 voltage, so please be careful about the safety design such as redundant design and
 malfunction prevention design which don't cause the damage expand even if they break
 down.
- 4. In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, life-support-related medical equipment, fuel control equipment and various kinds of safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement. Or consult with MPSD's sales department staff. (When semiconductor devices fail, as a result the semiconductor devices or wiring, wiring pattern may smoke, ignite, or the semiconductor devices themselves may burst.)
- 5. A semi-processed article is done now using solder which contains lead inside the semiconductor devices. There is possibility of the regulation substance depend on the applied models, so please check before using.
- 6. This specification is a material for component selection, which describes specifications of power semiconductor devices (hereinafter referred to as products), characteristic charts, and external dimension drawings.
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Minebea POWER SEMICONDUCTORS

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